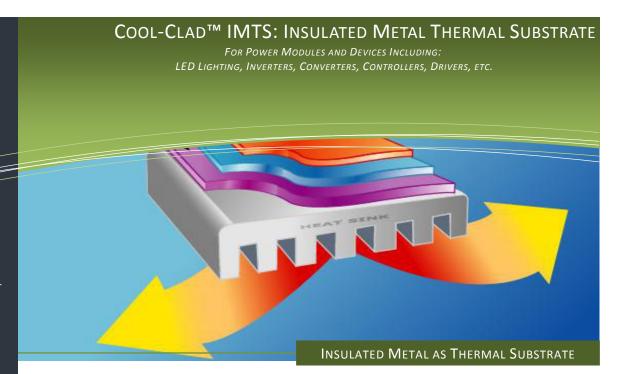


Choosing the proper thermal interface material from thermal greases, thermal gels, phasechange thermal pads and films or thermal adhesives is one of the most critical aspects of thermal management for long-term reliability. COOL-CLAD™ CXP and COOL-CLAD™ ESP represent the integration of the best dielectric adhesive with stress-relief capability and high temperature operation reliability that is embedded with the lowest thermal resistance interface material.

Al Technology (AIT) has more than 30 years of providing stateof-the-art materials and solutions for thermal management:

- Patented compressible phase-change thermal pads.
- Lowest thermal resistance thermal interface pads.
- Lowest thermal resistance greases and adhesives for thin bond line applications.
- Lowest thermal resistance diamond adhesives that were first used in supercomputers more than 15 years ago.



## Description of Cool-Clad™ Insulated Metal Substrate for Metal Core Printed Wiring Board

Insulated metal thermal substrates have been used to replace direct bonded copper (DBC) substrate for power modules and devices mostly for cost and flexibility. The effectiveness of the insulated metal, such as aluminum or copper as a thermal substrate, hinges on the dielectric adhesive layers to provide high thermal transfer from the POWER generated by the semi-conductor chip or component while maintaining high dielectric insulation. Any delaminating between the copper circuit trace from the metal heat spreading substrate will be detrimental for the performance in terms of temperature run away and thus dramatically shorten the useful life of the power device.

COOL-CLAD™ insulated metal thermal substrate (IMTS) is one of the proven thermal management material solutions that include COOL-BOND®, COOL-PAD™, COOL-SILVER™, COOL-GELFILM™, COOL-GREASE® and COOL-GEL® for the most stringent thermal dissipation applications.

AIT COOL-CLAD™ is comprised of a top circuit layer of 1-6 oz standard copper on either 60 mil thick aluminum or 30 mil copper. Other thicknesses of copper or aluminum are available on special order. COOL-CLAD™ CXP incorporates a novel high Tg and high strength thermally conductive cyanaester based thermal dielectric at 25 micron thickness to provide 2-3 time better thermal transfer in comparison to traditional 75 micron thick epoxy-based insulated metal substrate.

What distinguishes AIT COOL-CLAD™ CXP is the special dielectric layer that provides the following unparalleled thermal, dielectric and mechanical properties:

- 1. Ultra-low thermal resistance from copper circuit traces to the heat-spreader layer that is 20-100% lower than that achieved via an extra thin thermally conductive dielectric bond-line.
- COOL-CLAD™ CXP series is one of the first products in the industry with the capability to withstand
  processing of up to 350°C. The high Tg dielectric thermal bonding layer ensures the COOLCLAD™ IMTS for robust manufacturability and unparalleled long-term reliability.
- 3. The mechanical peel strength of over 6 lb-in maintains the highest mechanical integrity.
- Dielectric constant of less than 4.5 balances with high thermal conductivity of >2.0 W/m-K and more than 750V/mil dielectric strength to provide superior performance for even high frequency applications.
- 5. RoHS compliant that meets UL94V-0 rating.
- 6. Availability of thermal adhesive pre-preg to produce multi-layer circuits with the same high thermal conductivity and low thermal resistance between circuit layers.

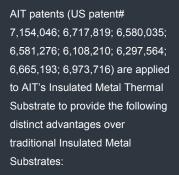
COOL-CLAD  $^{\text{TM}}$  ESP is a flexible epoxy based version available for flexible circuit application with a 2 oz copper base sheet.



## COOL-CLAD™: INSULATED METAL THERMAL SUBSTRATE

FOR METAL CORE PRINTED WIRING BOARDS IN POWER MODULES AND DEVICES INCLUDING:

LED LIGHTING, INVERTERS, CONVERTERS, CONTROLLERS, DRIVERS, ETC.



- Instead of a rigid fiberglass thermally conductive epoxy laminate, we use our proprietary flexible thermal dielectric insulating layer resulting in stress and warpfree thermal copper-clad laminates.
- Unparalleled thermal conductivity in the insulating layer by eliminating the fiberglass fabrics.
- High temperature stability to withstand soldering at 300°C.
- Multi-layer capability with the same flexible dielectric copper-clad pre-preg that can be laminated at less than 14 psi pressure and at 125°C or higher.
- Base metal plates with choice of aluminum and copper from 35 mils to 350 mils.
- Thinner insulated metal substrate and pre-preg are available in rolls of 12-inch width.
- Thicker insulated metal substrate and pre-preg are available in sheets of 18-20 inches by 24 inches.
- Ideal for power and LED components and modules.







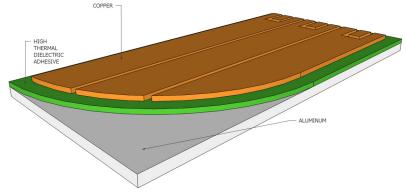
### PROVEN LOWER LED JUNCTION TEMPERATURE

## **Typical Properties of Cool-Clad™ CXP CC-AL Series (Aluminum Base Plate)**

PROPERTY/PARAMETER	VALUE
Electrical Resistivity of Dielectric Layer	>10 <sup>14</sup> ohm-cm
Dielectric Strength of Dielectric Layer @ 25 micron	>1000 V/mil
Glass Transition Temp. of Dielectric Layer (°C)	200
Peel Strength of Dielectric Layer (Pound/inch)	>6
Device Push-off Strength of Dielectric Layer (psi)	>3000
Hardness of Dielectric Layer (Type)	> 95 (D)
Cured Density of Dielectric (gm/cc)	2.5
Thermal Conductivity (Dielectric Layer)	3.0 W/m-°C
Linear Thermal Expansion Coefficient of Laminate (ppm/°C)	19
Maximum Continuous Operation Temp. (°C)	> 250

# <u>Typical Properties of Cool-Clad™ ESP Series CC-AL (Aluminum Base Plate)</u>

PROPERTY/PARAMETER	VALUE
Electrical Resistivity of Dielectric Layer	>10 <sup>14</sup> ohm-cm
Dielectric Strength of Dielectric Layer @75 micron	>1000 V/mil
Glass Transition Temp. of Dielectric Layer (°C)	-55
Peel Strength of Dielectric Layer (Pound/inch)	>3
Device Push-off Strength of Dielectric Layer (psi)	>1500
Hardness of Dielectric Layer (Type)	> 80 (A)
Cured Density of Dielectric (gm/cc)	2.5
Thermal Conductivity (Dielectric Layer)	3.0 W/m-°C
Linear Thermal Expansion Coefficient of Laminate (ppm/°C)	19
Maximum Continuous Operation Temp. (°C)	> 180

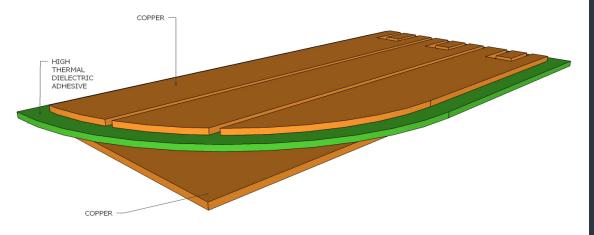


AI Technology, Inc. (© 2013, V 4.1) | 70 Washington Rd., Princeton Junction, NJ 08550 Tel: 609-799-9388 | <a href="www.aitechnology.com">www.aitechnology.com</a> | <a href="mailto:ait@aitechnology.com">ait@ait@aitechnology.com</a>

# COOL-CLAD™: INSULATED METAL THERMAL SUBSTRATE

METAL CORE PRINTED WIRING BOARDS FOR POWER MODULES AND DEVICES INCLUDING: LED LIGHTING, INVERTERS, CONVERTERS, CONTROLLERS, DRIVERS, ETC.





### PROVEN LOWER LED JUNCTION TEMPERATURE

### **Typical Properties of Cool-Clad™ CXP CC-CU Series (Copper Base Plate)**

PROPERTY/PARAMETER	VALUE
Electrical Resistivity of Dielectric Layer	>10 <sup>14</sup> ohm-cm
Dielectric Strength of Dielectric Layer @ 25 Micron Thickness (Volts/mil)	>1000 V/mil
Glass Transition Temp. of Dielectric Layer (°C)	200
Peel Strength o Dielectric Layer (Pound/inch)	>6
Device Push-off Strength of Dielectric Layer (psi)	>2000
Hardness of Dielectric Layer (Type)	> 95 (D)
Cured Density of Dielectric Layer (gm/cc)	2.5
Thermal Conductivity of Dielectric Layer	3 W/m-°C
Linear Thermal Expansion Coefficient of Laminate (ppm/°C)	19
Maximum Continuous Operation Temp. (°C)	250

# <u>Typical Properties of Cool-Clad™ ESP CC-CU Series for Flexible Circuits</u>

PROPERTY/PARAMETER	VALUE
Electrical Resistivity of Dielectric Layer	>10 <sup>14</sup> ohm-cm
Dielectric Strength of Dielectric Layer @ 75 Micron Thickness (Volts/mil)	>1000 V/mil
Glass Transition Temp. of Dielectric Layer (°C)	-55
Peel Strength (Pound/inch)	>3
Device Push-off Strength of Adhesive Layer (psi)	>1500
Hardness of Adhesive Layer (Type)	> 80 (A)
Cured Density of Dielectric of Adhesive Layer (gm/cc)	2.5
Thermal Conductivity of Adhesive Layer	3 W/m-°C
Linear Thermal Expansion Coefficient of Laminate (ppm/°C)	19
Maximum Continuous Operation Temp. (°C)	> 180

AIT Cool-Clad™ copper-clad laminate substrate and copper-clad pre-preg panels used for multi-layered insulated metal substrate circuits can be handled in exactly the same method and infrastructure as commonly used in standard PWB and flex circuit.

#### Panel & Roll Copper-clad Material Handling

- Cool-Clad<sup>™</sup> copper-clad laminate substrates can be stored in ambient conditions for at least 12 months.
- Cool-Clad™ pre-preg can be stored in ambient conditions for at least 6 months.

#### Panel Prep

- Tooling/Registration
- Scrubbing
- Chemical Cleaning
- Base Metal Protection

#### **Imaging**

- Dry Film Application
- Wet Film Application
- Screened Image
- Application

### Wet Chemistry Processing

- Etching
- Stripping
- Post Etch/Strip Clean

#### Solder Mask Application

- Screen, Spray or Curtin Coat
- Thermal Solder Mask
- UV Cured Solder Mask

#### Second Step Drill or Punch

#### Finishing Operation

- HASL
- OSP
- Tin
- Ni/Au

#### Finishing Fabrication

- Rout
- Score
- Punch

Precision circuitry of 1-mil line and 1-mil spacing can easily be etched with the CHIP-COUPLER™ substrate technology for solder-able and moisture resistant interconnections.

## COOL-CLAD™ IMTS: INSULATED METAL THERMAL SUBSTRATE

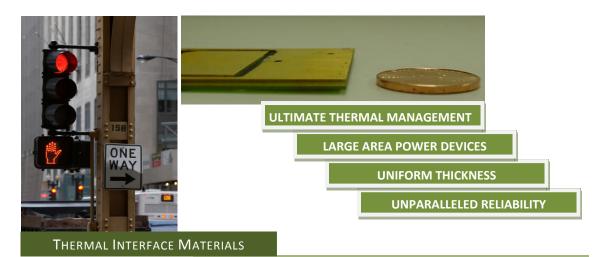
FOR POWER MODULES AND DEVICES INCLUDING: LED LIGHTING, INVERTERS, CONVERTERS, CONTROLLERS, DRIVERS, ETC.



### Typical Multi-Layer Processing Parameters for Cool-Clad™

PRE-PREG PROCESSING FOR COOL-CLAD ESP	ESP7455-PP
Storage and Shelf Life	Ambient in original package
Lamination Temperature, Pressure and Time	150-175°C/10-15 psi/>30 second
Post Curing (Without Pressure)	Same temperature as lamination

PRE-PREG PROCESSING FOR COOL-CLAD CXP	CXP7685-PP
Storage and Shelf Life	Ambient in original package
Lamination Temperature, Pressure and Time	150-175°C/10-15 psi/>30 second
Post Curing (Without Pressure)	Same temperature as lamination



### AIT Thermal Interface Materials for IMTS, High Power Devices, HB LED Applications:

FUNCTION	AIT PART #	THERMAL, ELECTRICAL & other RELEVANT PROPERTIES
Die-Attach Adhesive	PRIMA-BOND™ MC7665-LED	Thermally conductive, white reflective, electrically insulating die-attach for HB LED chips  Lowest thermal resistance, ambient storable single component
Thermal Adhesive Film	COOL-BOND™ CB7135	Low thermal resistance, electrically insulating interface pad     Compressible, instant melt-bonding phase-change adhesive
Thermal Epoxy Film	COOL-BOND™ RTK7555	Low thermal resistance, electrically insulating interface pad     Compressible, rapid heat curing tacky film adhesive
Thermal Paste Adhesive	COOL-BOND™ HB-2	Low thermal resistance, electrically insulating interface paste adhesive     Flexible for large area bonding & field repair, 1:1 mix, ambient curing
Compressible Thermal Pad	COOL-PAD™ CPR7065-LB	Low thermal resistance interface, electrical insulating pad     Compressible, phase-change interface pad
Thermal Interface	COOL-SILVER™ PAD	Lowest thermal resistance, electrically non-conductive interface     Compressible, phase-change interface pad
Conductive Grease	COOL-GREASE™ CGR8550	Non-curing, electrically conductive interface grease for moving parts     Lowest thermal resistance non-silicone grease, proven reliability
Thermal Grease	COOL-GREASE™ CGR7559-LB	Lowest thermal resistance, electrically insulating interface grease     Non-curing, non-silicone, proven long-term stability
Gel like film to replace grease	COOL-GELFILM™	Lowest thermal resistance, electrically insulating interface tape     Non-curing, non-silicone, proven long-term stability to replace grease
PSA on passive side	COOL-GAPFILL™	Lowest thermal resistance, electrically insulating interface gap filling pad of 10-100 mils thickness     Non-curing, non-silicone, proven long-term stability

Call Al Technology at 609-799-9388 for more information on this product and our full line of electronic processing and packaging materials!

#### About Al Technology, Inc.

Since pioneering the use of flexible epoxy technology for microelectronic packaging in 1985, Al Technology (AIT) has been one of the leading forces in developing advanced materials and adhesive solutions for electronic interconnection and packaging.

Besides pioneering the use of "phase-change" materials (PCM) as thermal interface materials (TIM), AIT has provided the microelectronic packaging industry with its flexible epoxy thermal adhesives. By managing interfacial stress induced by differential coefficient of thermal expansion between bonding adherents, these thermal management materials have found extensive use and success in critical military and aerospace applications.

The same stress-free dielectric adhesives are now adapted for use in insulated metal substrates with copper and aluminum clad. The key advantage of these thermal management materials is their unparalleled long-term reliability attributed to their ability to withstand repeated thermal cycling and stress-free bonding between the heat-spreader plate and the circuit layer. AIT also offers the same flexible epoxy pre-preg with high thermal conductivity for more advanced multilayer insulated metal substrate circuits and modules. This novel class of thermal management materials provides a platform and infrastructure for large area thermal management of power modules such as solar cells, LED panels,

AIT has a full line of die and substrate attach films and pastes, thermal interface materials, (EMI/RFI) mitigation material solutions, conductive caulks and adhesives and advanced flexible and Insulated Metal Circuit Substrates. AIT is located in a ISO9001:2000 certified manufacturing and R&D facility on a 16-acre campus in Princeton Junction, NJ. Sales support includes company direct offices in Shenzhen-HK China and sales reps in Europe and Asia.